

Development of scalable Silicon quantum computer technology

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Performers Takashi Nakajima, RIKEN

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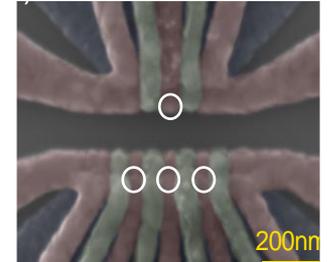
Michihisa Yamamoto, RIKEN/Tokyo Univ.

Shintaro Takada, AIST

Scenario for Achieving the MS Goal

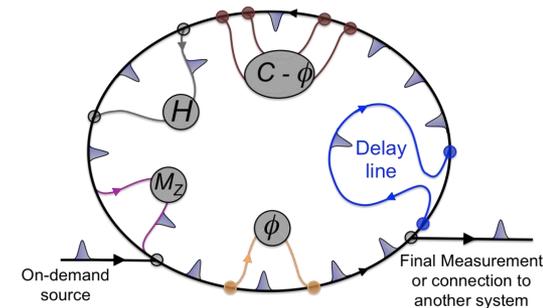
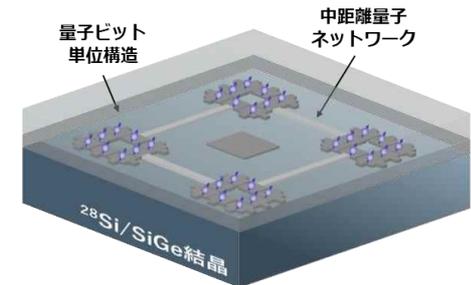
Milestones

Build technology bases of implementing scalable multi-qubit devices toward development of large-scale QC **in collaboration with semiconductor industries**, and also **demonstrate the proof of quantum error correction** optimized for semiconductor QC.



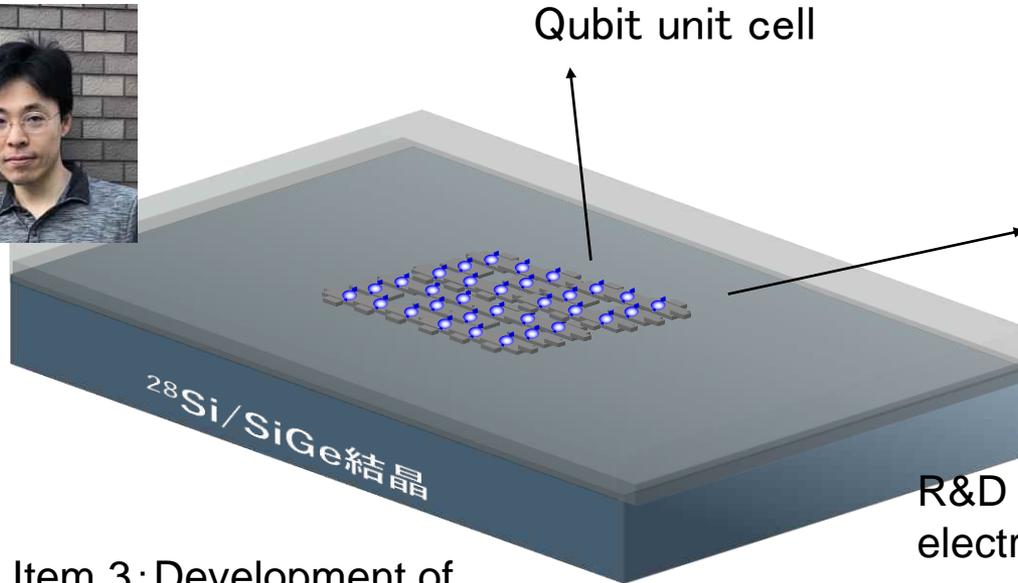
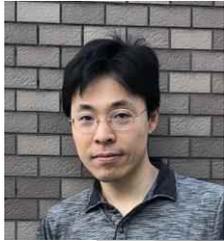
Challenges

- (1) Scale-up: Building blocks of qubit layout
Middle-distance quantum link
- (2) Substrate quality and valley: Interface control of large-area $^{28}\text{Si}/\text{SiGe}$
- (3) Error correction: Optimized QEC code for biased noise ($T_1/T_2^* > 10^3$ to 4)
...in collaboration with MS theory project
- (4) Wiring: Multilayer interconnection, 3D wiring, Integration with cryo-electronics
... in collaboration with industry and MS exp. project
- (*) Fridges, Auto-tuning, Cost, Engineers,...
- (5) Alternative approach: New method using flying qubits of electron wave packets

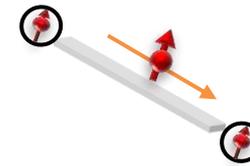


R&D Items in the Project

R&D Item 1 : Development of scalable technologies for fault-tolerant Si spin qubits
T. Nakajima, RIKEN



R&D Item 2 : Development of middle-distance quantum link
T. Fujita, Osaka-U

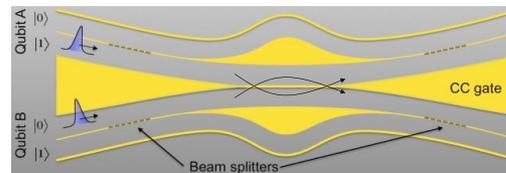


Qubit shuttle

R&D Item 3 : Development of isotopically controlled Si/SiGe substrate technology
S. Miyamoto, Nagoya-U



R&D Item 4: Development of electron wave-packet qubits with new principle
M. Yamamoto, RIKEN/Tokyo-U
S. Takada, AIST



Progresses since Oct. of 2022

- Installation of large-scale facilities, big dilution fridges, electronics, crystal growth machine,... in end of 2023 through beginning of 2024.

> 100 qubits



- Starting programs in each PI.

T. Nakajima: Developing multi-qubit devices prototypes (4 to 10 qubits) and improving qubit control technology

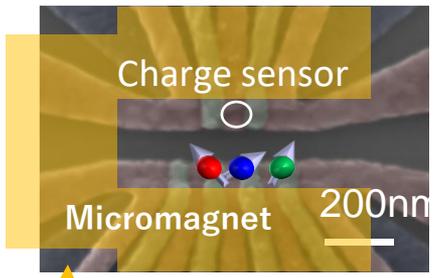
T. Fujita: Fabricating quantum dot arrays for a transport channel

S. Miyamoto: Studying Si/SiGe interface control technology

M. Yamamoto, S. Takada: Developing generation and control technology of wave packet propagation

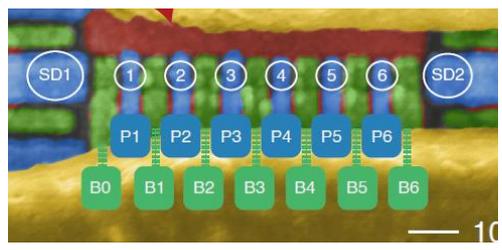
R&D Item 1 Development of scalable technologies for fault-tolerant Si spin qubits

T. Nakajima, RIKEN



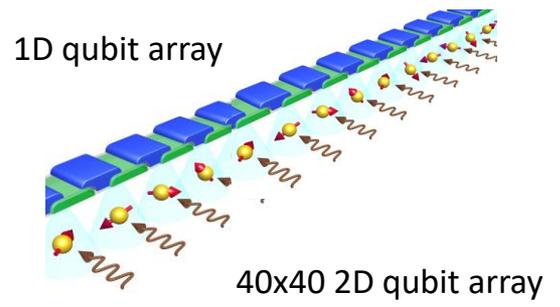
microwave

Nat. Nanotechnol. 2021
Nature 2022

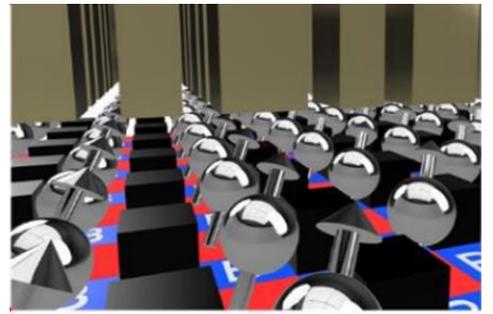


100nm

Nature 2022 (TuDelft)

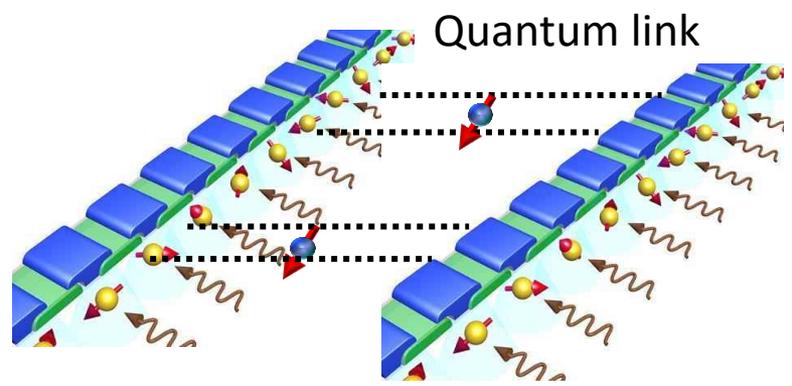


40x40 2D qubit array



Sci. Rep. 2021

Scaling up by interconnecting
1D qubit arrays

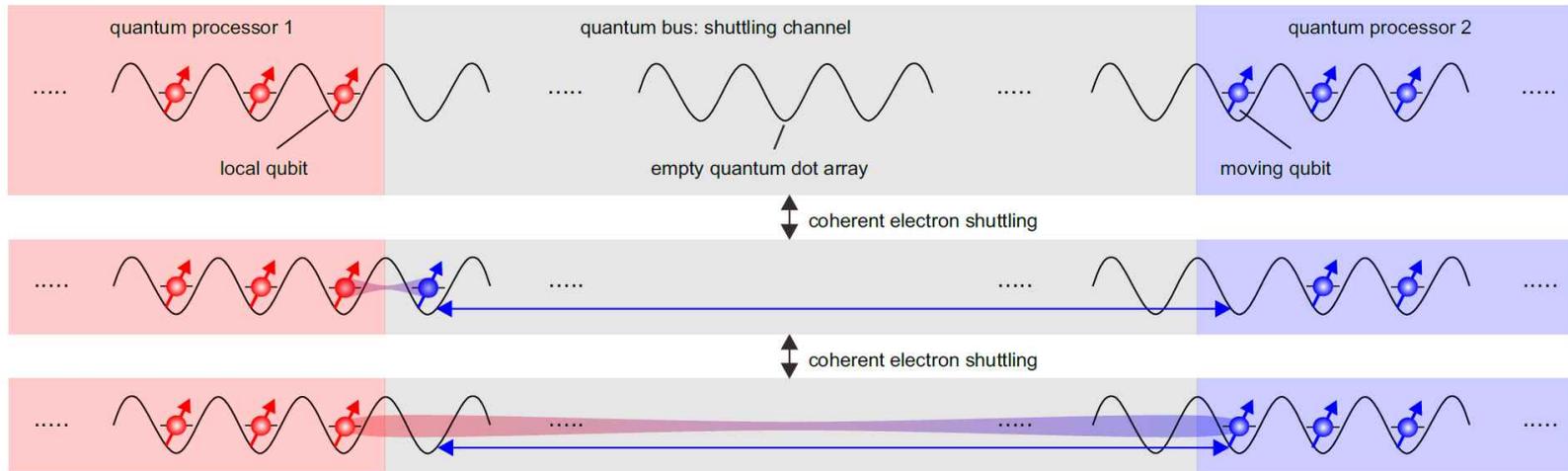


- Device structure allowing for qubit initialization, readout, and application of microwaves / gate pulses
- Wiring to dense gate electrodes
- Demonstration of basic error correction codes

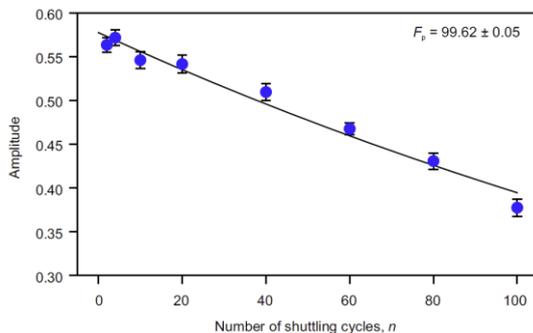
R & D Item 1 Progress

Purpose:

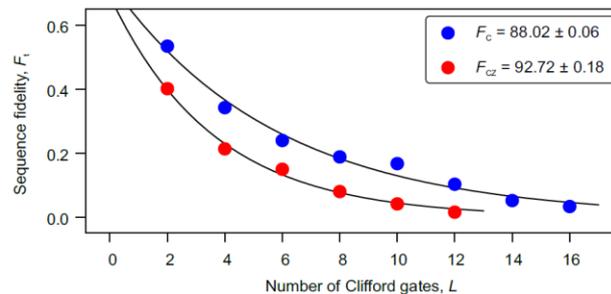
To interconnect qubit arrays, a two-qubit gate is implemented using spin shuttling



Coherent spin shuttling



2Q gate fidelity evaluated with randomized benchmarking

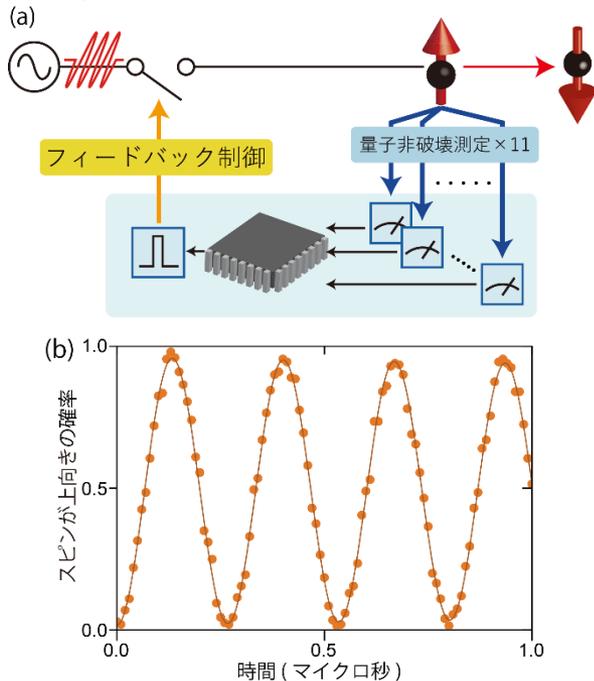


Achievements:

1. Coherent spin shuttling with 99.6% fidelity
2. Shuttling-based CZ gate with 93% fidelity

R & D Item 1 Progress

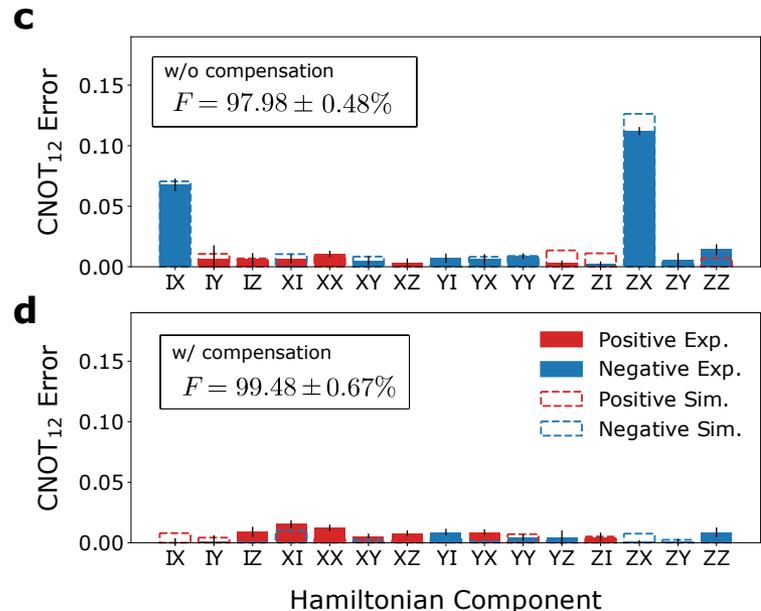
Purpose:
High-fidelity initialization of qubits decoupled from reservoirs



T. Kobayashi *et al.*, npj Quantum Info. 9 52 (2023)

Achievements:
99% initialization fidelity with repeated measurements and active reset

Purpose:
Error analysis with GST for high-fidelity 2Q gates



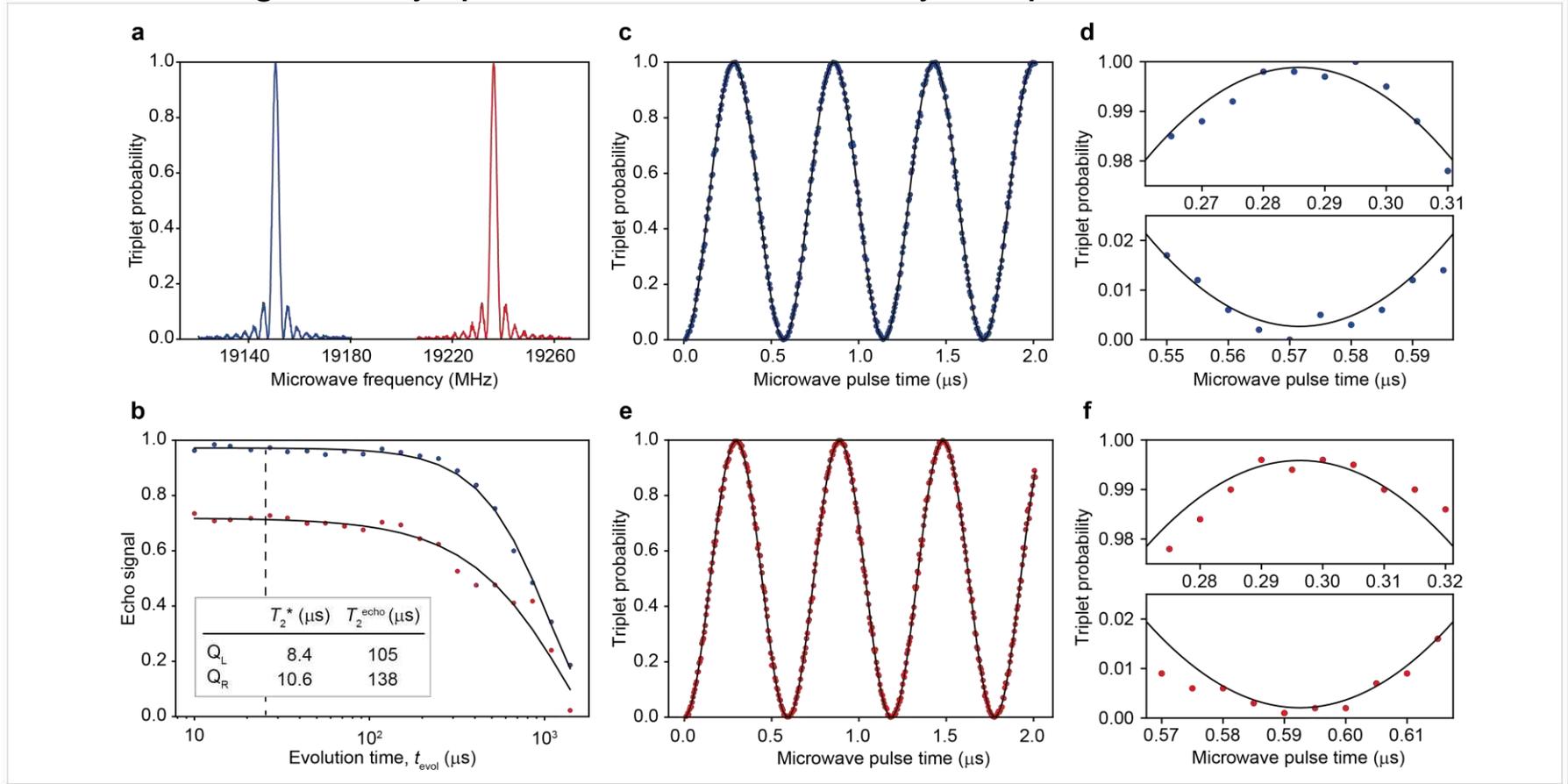
Yi-Hsien Wu *et al.*, submitted

Achievements:
99.4% 2Q gate fidelity with systematic error calibrations

R & D Item 1 Progress

Purpose:

Fast and high-fidelity qubit readout is necessary for quantum error correction



K. Takeda *et al.*, submitted

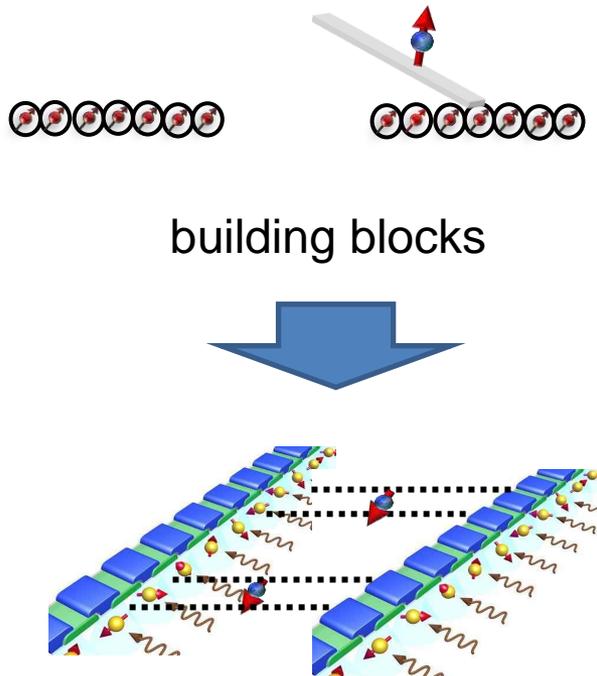
Achievements:

SPAM fidelity 99.8% with 3 μs readout time, applicable to QEC

R & D Item 1 Outlook

In FY2023, we aim to

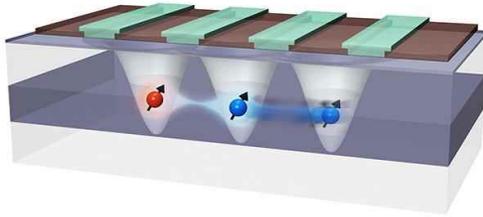
1. Design, fabricate, and characterize building blocks of sparse qubit array structures
2. Start high-fidelity qubit control experiments with more than 4 qubits



R&D Item 2 Development of middle-distance quantum link

T. Fujita, Osaka-U

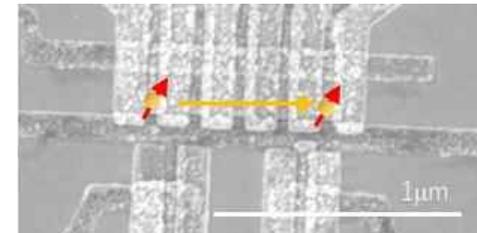
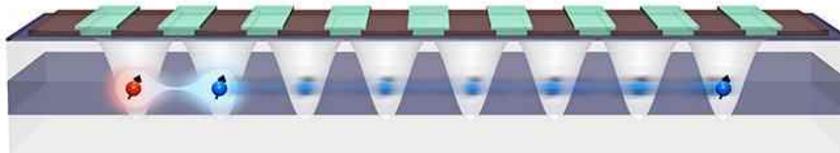
Shuttling quantum bits and two-qubit gate operation



npj Quantum Info. 2017 (T. Fujita, Delft)
Nat. Commun. 2022 (A. Noiri, Riken)

Quantum link using one-dimensional quantum-dot arrays

Basic structure



Linking small-scaled quantum processors

Scale-up



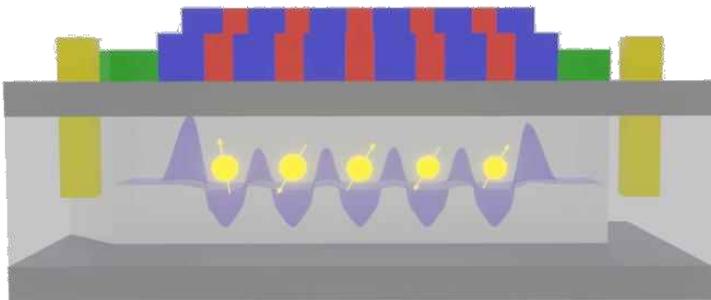
Middle-distance quantum network

R & D Item 2 Progress

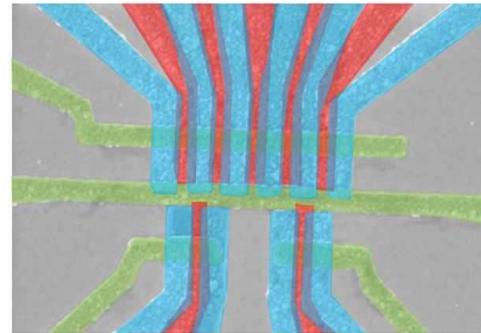
Purpose:

1. Overlapping gate electrode development
2. Simulation of qubit transfer in quantum links

Schematic of dot-array potential, efficiently formed by overlapping gates



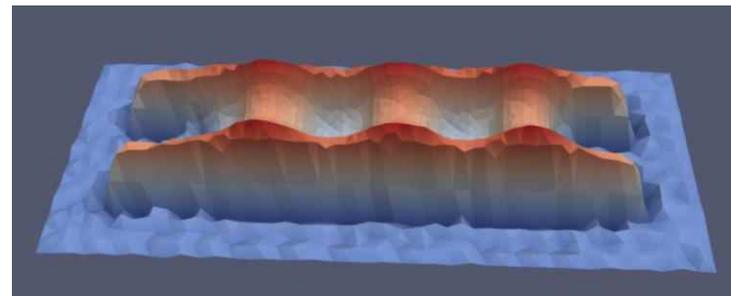
SEM picture of alignment test



1st layer: separation gates
2nd layer: dot gates
3rd layer: barrier gates

500 nm

Conveyor mode potential simulation



Achievements:

1. Overlapping electrode fabrication using Al gates
2. Calculation of time dependent potential and wavefunction (e.g. Conveyor mode, spin chain)

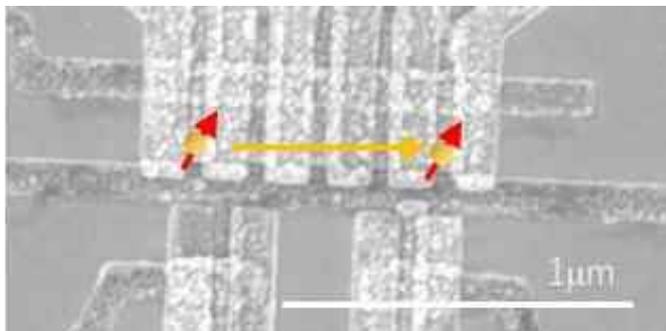
R & D Item 2 Outlook

Scopes:

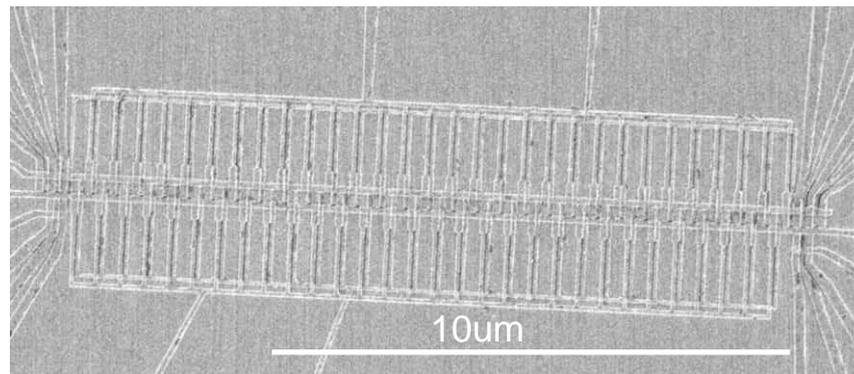
- Increasing number of dots per link
- Benchmarking quantum links
- Distant two-qubit operations

Aims for 2023:

- Start measurement for qubit transfer in a 5-dot device



Over-10-dot array link development using periodic gates



Preparing:

- Test-device fabrication (GaAs)
- Setting up equipment for qubit transfer evaluation
- Collaboration for transitioning to Si material

R&D Item 3 Development of isotopically controlled Si/SiGe substrate technology

S. Miyamoto, Nagoya-U

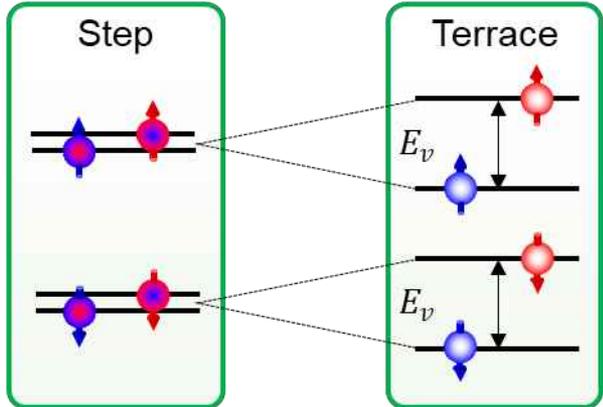
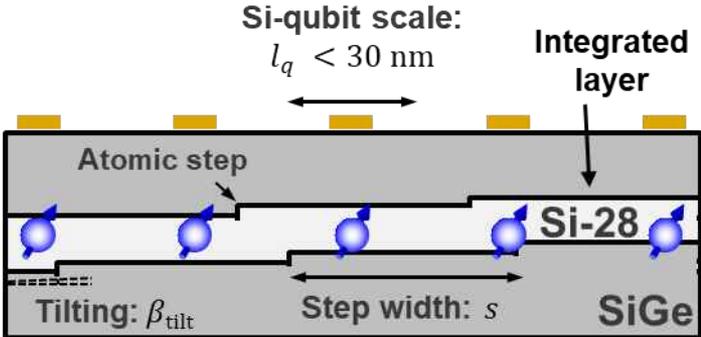
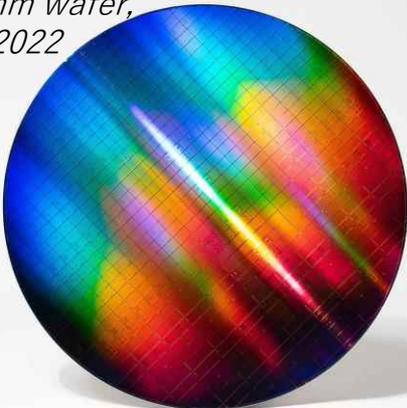
Large-scale implementation of Si quantum platform satisfying fault-tolerance

- High-quality Si-28/SiGe isotope crystal*
- Atomic-scale interface control technology

*Pioneering work on Si-28 Crystal (Keio)

*IEDM Technical Digest 2018
(S. Miyamoto, Keio)

*QDs in 300mm wafer,
Intel report 2022*

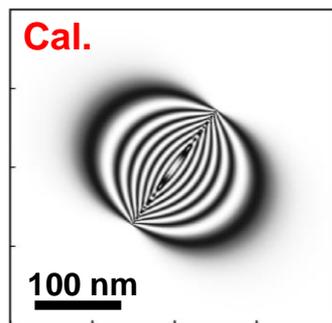
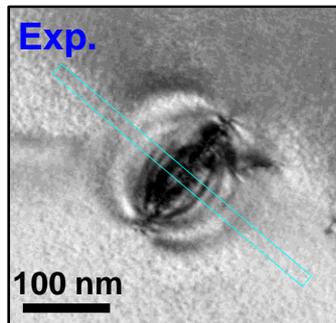
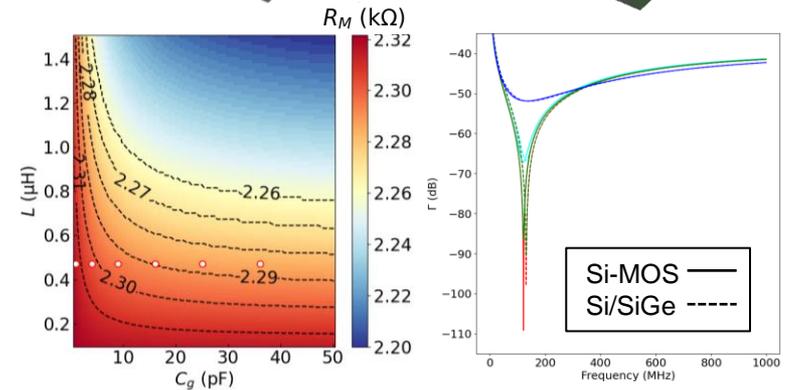
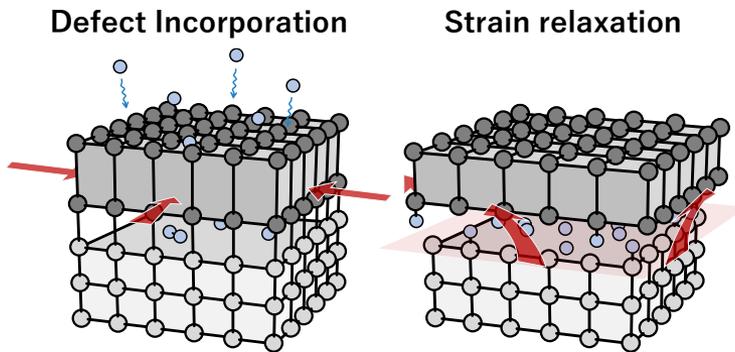
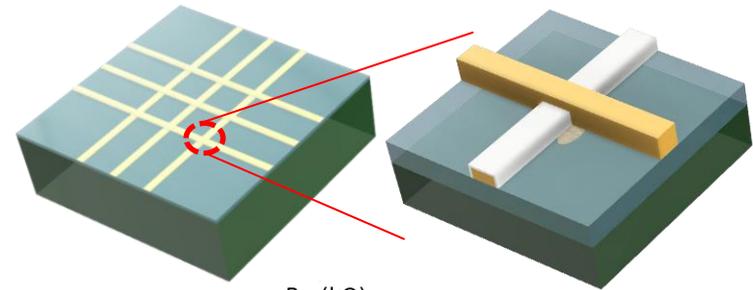


Spin-valley system

R & D Item 3 Progress

Purpose:

1. Interface control technology for high-quality Si-28/SiGe crystals
2. Wafer evaluation technology for large-scale isotope crystals



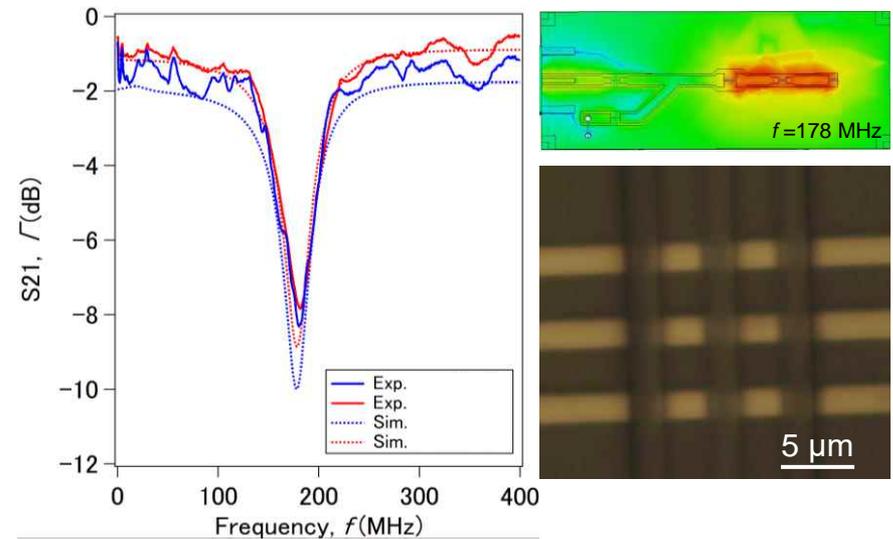
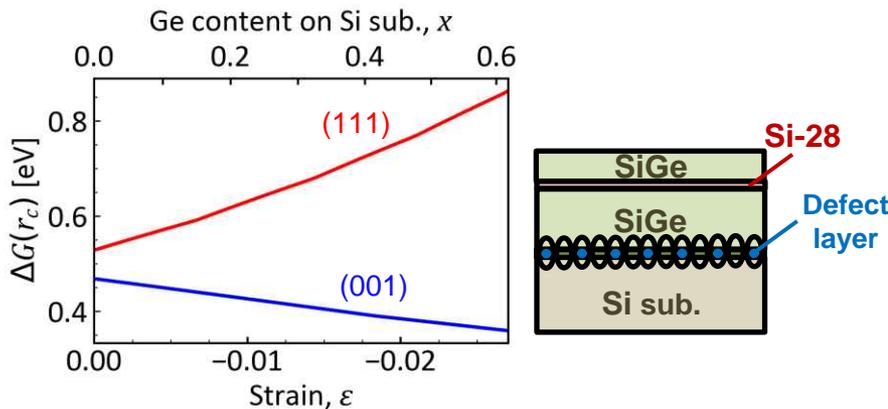
Achievements:

1. Proposal on interface step control utilizing defect engineering
2. Exploring high-frequency scheme for internal-noise evaluation

R & D Item 3 Outlook

Scopes:

1. Principle verification of interface control technology
2. Foundation building of large-scale process & evaluation technology



Preparing:

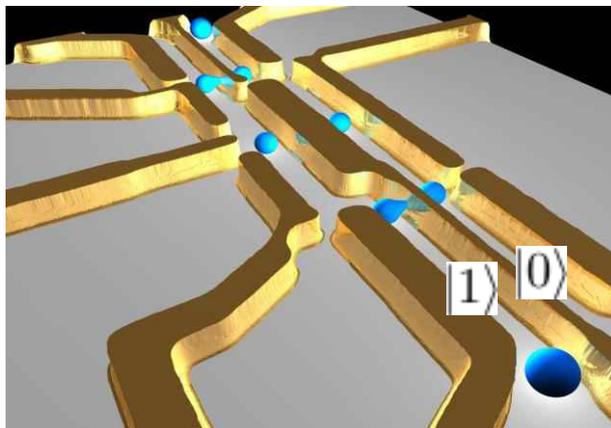
- CVD manufacturing systems enabling Si isotope control
- Prototype design for realizing ultra-flat Si-28/SiGe structure
- Lateral expansion of high-freq. meas. & scalable gate technique

R&D Item 4 Development of electron-wave-packet qubits with a new principle

M. Yamamoto (RIKEN/Tokyo-U), S. Takada (AIST)

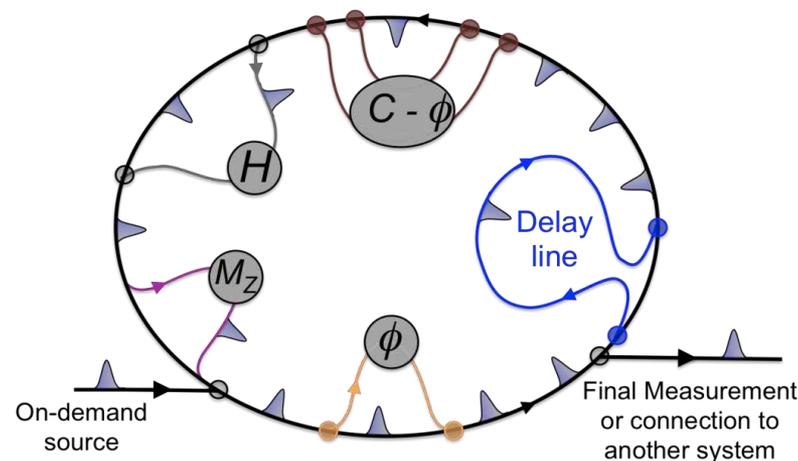
Flying qubits of electron wave packets

2-path interferometer: Quantum operation circuit



M. Yamamoto et al.,
Nature Nano. 7, 247 (2012)

New-concept quantum computer



Highly efficient hardware (No requirement to wire all individual qubits) → **Possibility to realize a fault tolerant quantum computer with a few thousand wires (in a single dilution fridge)**

Research topics

- Demonstration of high-fidelity flying qubit operations
- Understanding of properties of electron wave packets

1D electron wave packets: Low energy relaxation

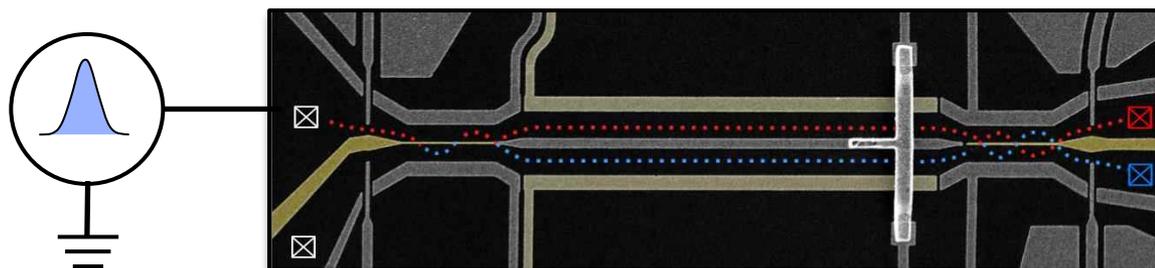


G. Roussely, S. Takada et al.,
Nature Commun. 9, 2811 (2018)

R & D Item 4 Progress outline

- **Observed suppression of decoherence for injection of short electrical pulses**

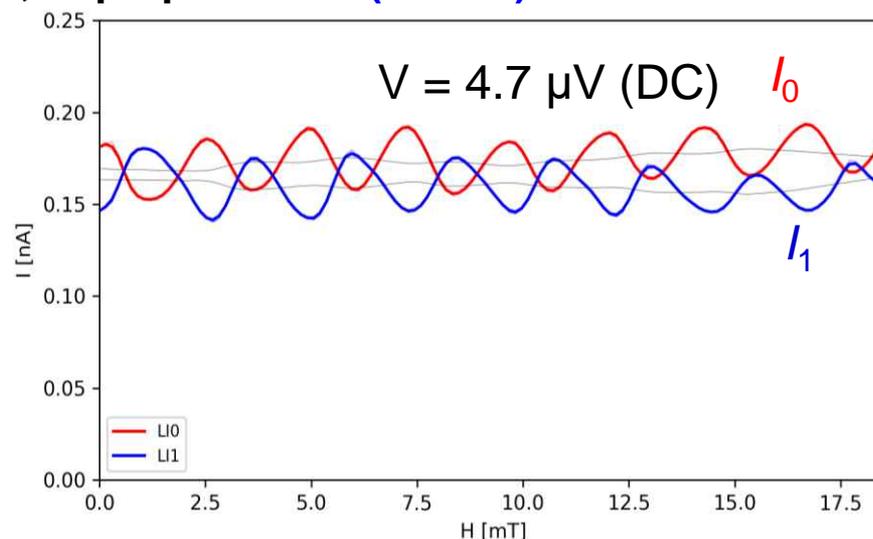
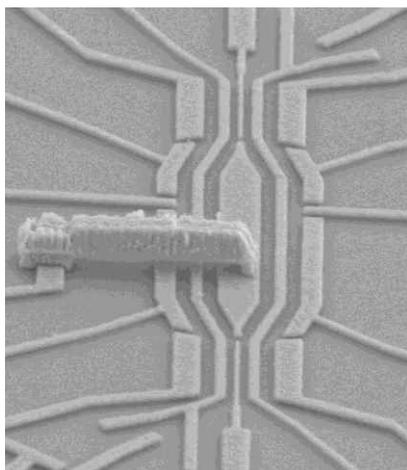
M. S. Ouacel, et al., in preparation (in collaboration with Institute NEEL, CNRS)



I_0 shorter pulse
→ higher visibility
 I_1 (one order of magnitude)

- **Realized a scalable two-path interferometer (quantum circuit) consisting of only one transmitting channel with strong Coulomb interaction**

D. Pomaranski, et al., in preparation. (RIKEN)



$\sim e^2/h$

Visibility tunable
with Coulomb
interaction (V_g)

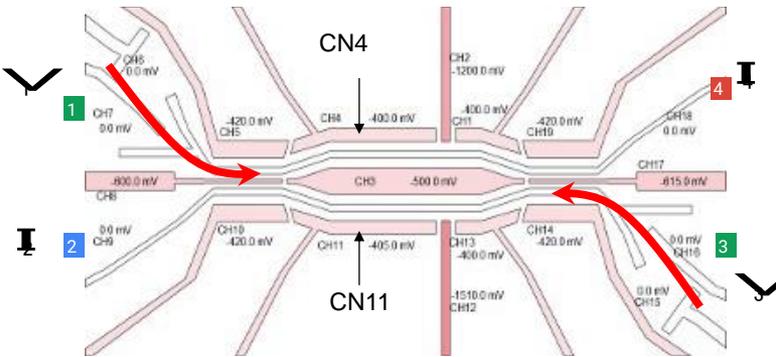
- **Tuned the plasmon velocity by *local* gates**

S. Takada, et al., in preparation. (AIST)

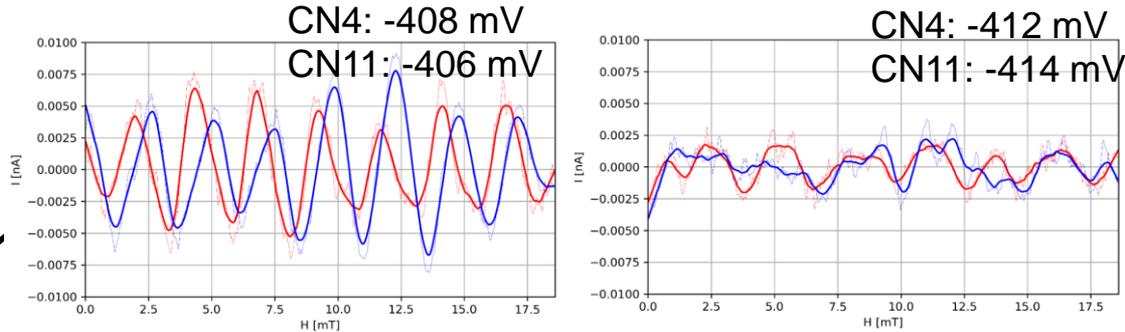
R & D Item 4 Progress

1. Developed highly controllable quantum circuit consisting of a single channel (shown in the previous slide)
2. Investigated Coulomb interaction between electrons in the circuit, which is useful for two qubit gates made out of crossing wave packets.
3. Developed new method to control the velocity of electron wave packets v_p

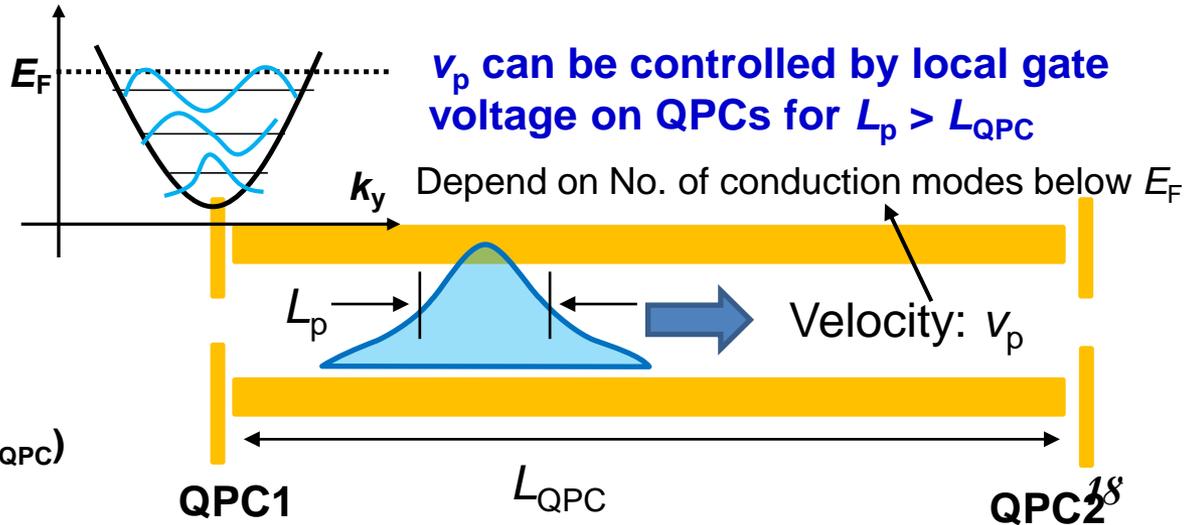
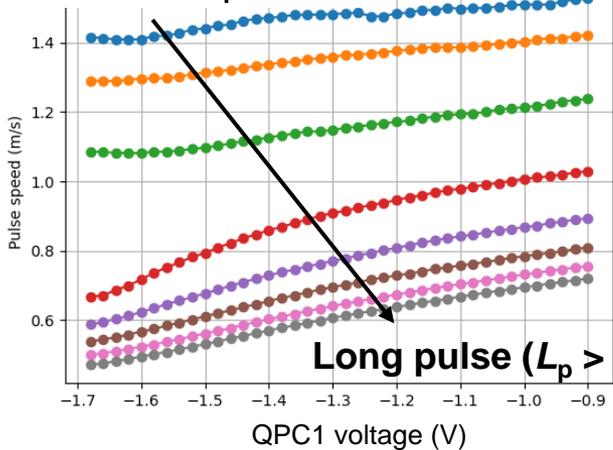
2-particle injection



Visibility change by the channel width (via Coulomb)
(only phase shift expected for the non-interacting case)



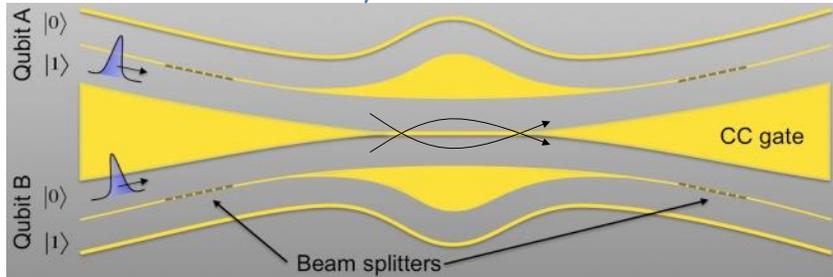
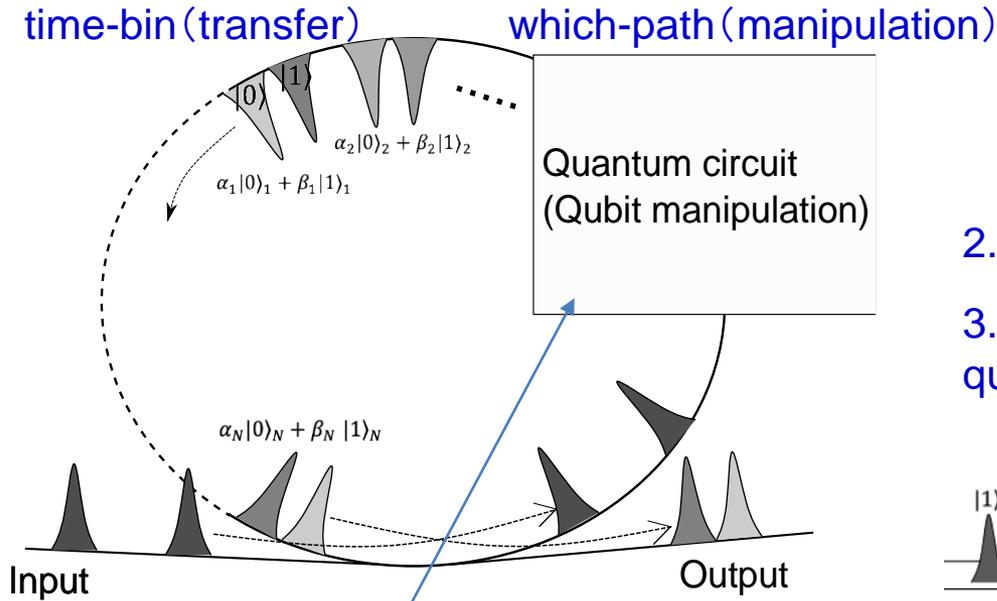
Short pulse ($L_p < L_{QPC}$)



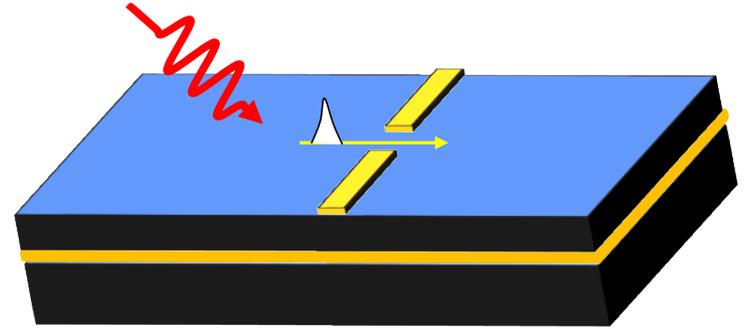
R & D Item 4 Outlook

PCT/JP2023/025244 (submitted on 7th July)

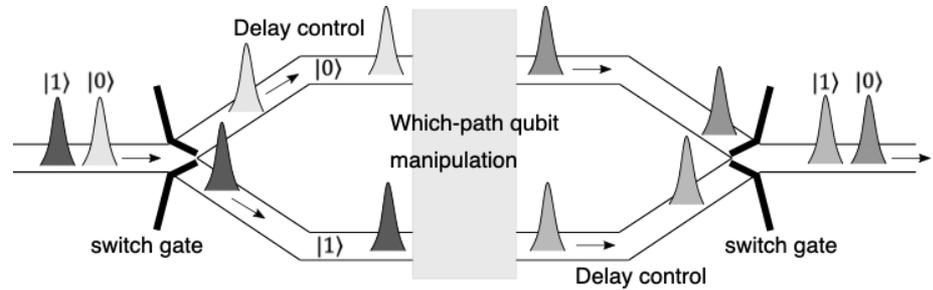
“A universal quantum computer using time-bin encoding of electron wave packets in loop circuits”



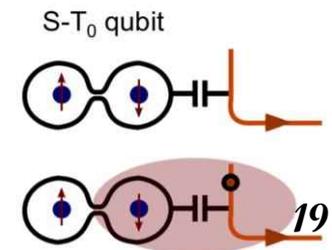
1. Generate ultrashort electron wave packet by converting light pulse to electron pulse



2. Realize high fidelity quantum operation
3. Demonstrate long coherence of a time-bin qubit of an electron wave packet



4. Readout a single wave packet using a spin qubit



Summary

